

GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER MODULE, 6 - 10 GHz OUTPUT

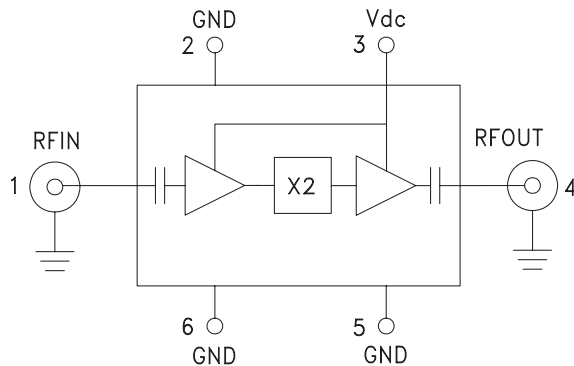


Typical Applications

The HMC-C031 is suitable for:

- Wireless Local Loop
- Point-to-Point & VSAT Radios
- Test Instrumentation
- Military & Space

Functional Diagram



Features

- High Output Power: +17 dBm
- Low Input Power Drive: -2 to +6 dBm
- 100 KHz SSB Phase Noise: -140 dBc/Hz
- Single Supply: +5V@ 90 mA
- Hermetically Sealed Module
- Field Replaceable SMA Connectors
- 55° to +85°C Operating Temperature

General Description

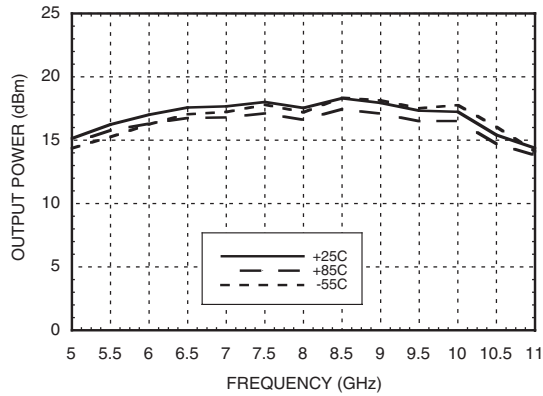
The HMC-C031 is a x2 active broadband frequency multiplier utilizing GaAs PHEMT technology in a miniature hermetic module. When driven by a 3 dBm signal, the multiplier provides +17 dBm typical output power from 6 to 10 GHz. The F_o and $3F_o$ isolations are 12 dBc with respect to output signal level. This frequency multiplier features DC blocked I/O's, and is ideal for use in LO multiplier chains for Pt to Pt & VSAT Radios yielding reduced parts count vs. traditional approaches. The low additive SSB Phase Noise of -140 dBc/Hz at 100 kHz offset helps maintain good system noise performance.

Electrical Specifications, $T_A = +25^\circ C$, $V_{dc} = +5V$, 3 dBm Drive Level

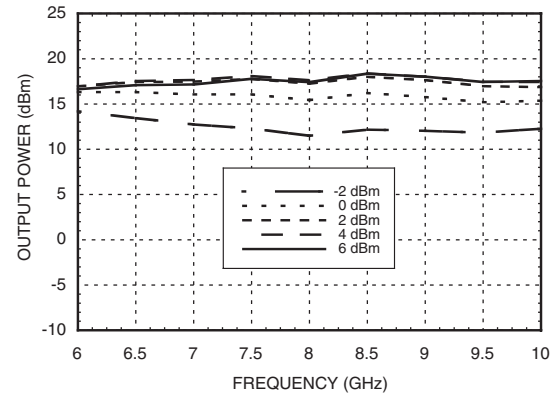
Parameter	Min.	Typ.	Max.	Units
Frequency Range, Input	3 - 5			GHz
Frequency Range, Output	6 - 10			GHz
Output Power	14	17		dBm
F_o Isolation (with respect to output level)		12		dBc
$3F_o$ Isolation (with respect to output level)		12		dBc
Input Return Loss		20		dB
Output Return Loss		14		dB
SSB Phase Noise (100 kHz Offset)		-140		dBc/Hz
Supply Current		90		mA

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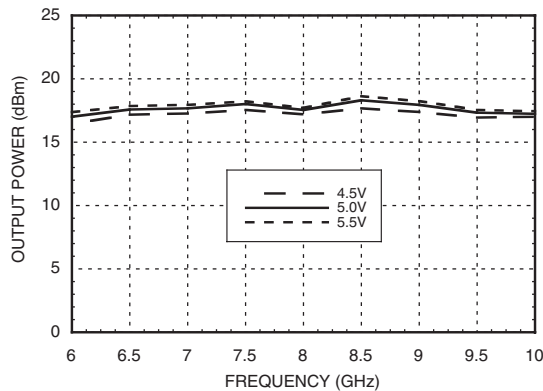
Output Power vs. Temperature @ 3 dBm Drive Level



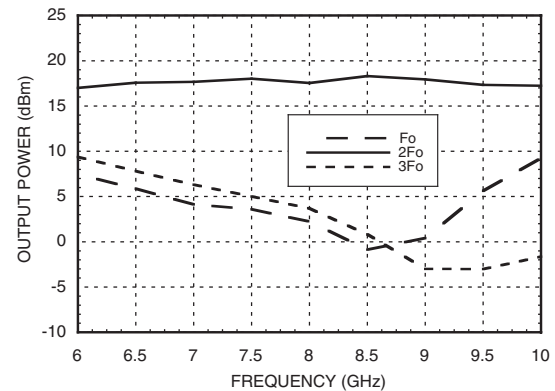
Output Power vs. Drive Level



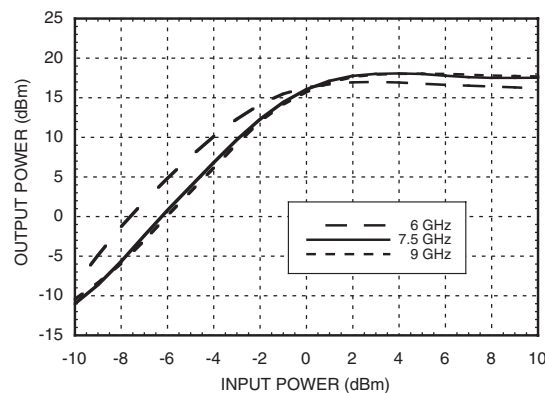
Output Power vs. Supply Voltage @ 3 dBm Drive Level



Isolation @ 3 dBm Drive Level

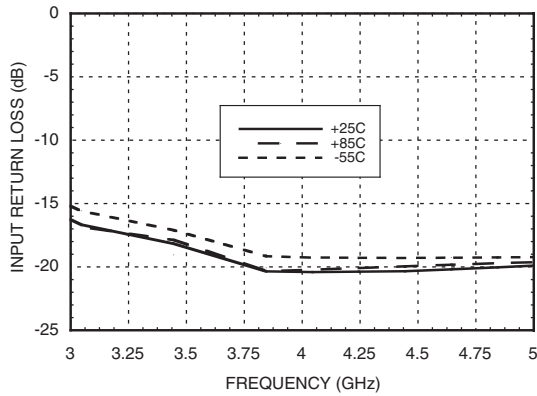


Output Power vs. Input Power

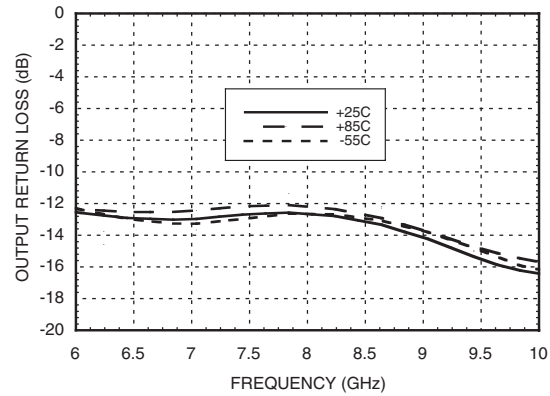


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Input Return Loss vs. Temperature @ 0 dBm Drive Level



Output Return Loss vs. Temperature @ 0 dBm Drive Level



Absolute Maximum Ratings

RF Input (Vdc = +5V)	+13 dBm
Bias Supply Voltage (Vdc)	+6.0 Vdc
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C

Typical Supply Current vs. Vdd

Vdd (Vdc)	Idd (mA)
4.5	89
5.0	90
5.5	91

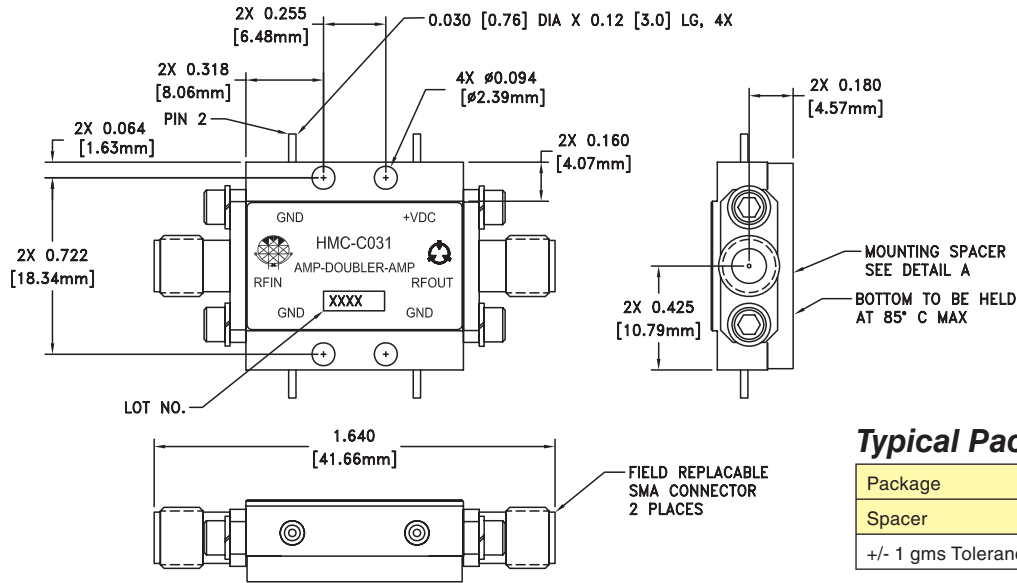
Note:
Multiplier will operate over full voltage range shown above.



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

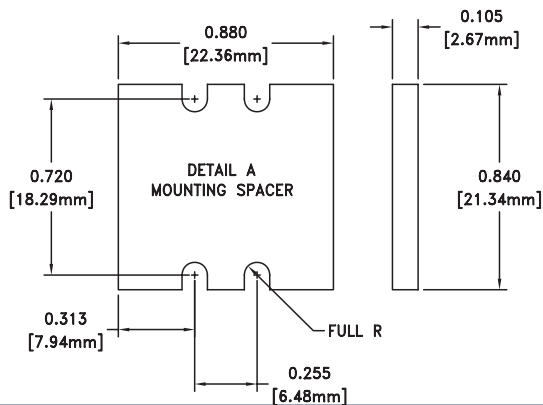
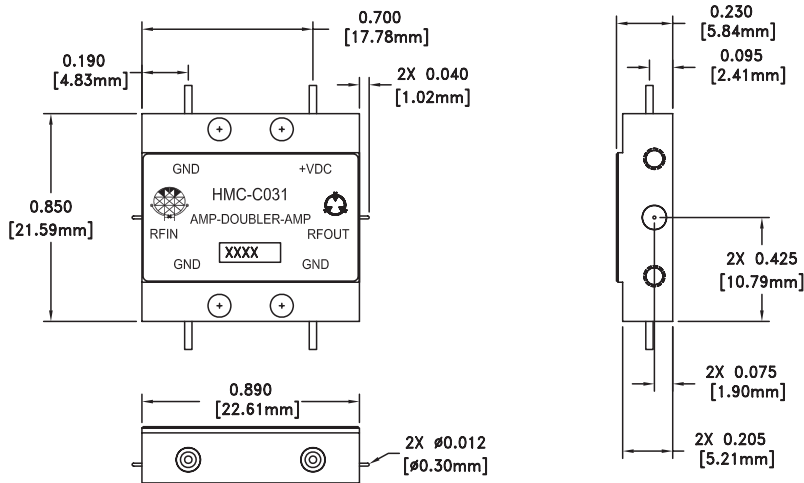
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Outline Drawing



Typical Package Weight

Package	18.7 gms
Spacer	3.3 gms
+/- 1 gms Tolerance	



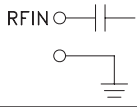

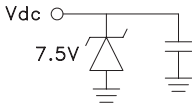
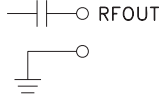
NOTES:

1. PACKAGE, LEADS, COVER MATERIAL: KOVAR
2. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 75 MICROINCHES MIN.
3. MOUNTING SPACER: NICKEL PLATED ALUMINUM
4. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]
5. TOLERANCES: 0.010 [0.25] UNLESS OTHERWISE SPECIFIED

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
20 Alpha Road Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373
Order Online at www.hittite.com

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Pin Description

Pin Number	Function	Description	Interface Schematic
1	RFIN and RF Ground	Pin is AC coupled and matched to 50 Ohms from 3 - 5 GHz. RFIN uses a female SMA connector.	
2, 5, 6	GND	One of these pins must be connected to power supply ground.	
3	Vdc	Power supply voltage for the amplifier includes a 7.5V zener diode for over voltage and negative voltage protection	
4	RFOUT and RF Ground	Pin is AC coupled and matched to 50 Ohms from 6 - 10 GHz. RFOUT uses a female SMA connector.	

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Notes: